

2SD1979

Silicon NPN epitaxial planar type

For low frequency amplification

For muting

For DC-DC converter

■ Features

- Low ON resistance R_{on}
- High forward current transfer ratio h_{FE}
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	50	V
Collector-emitter voltage (Base open)	V_{CEO}	20	V
Emitter-base voltage (Collector open)	V_{EBO}	25	V
Collector current	I_C	300	mA
Peak collector current	I_{CP}	500	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

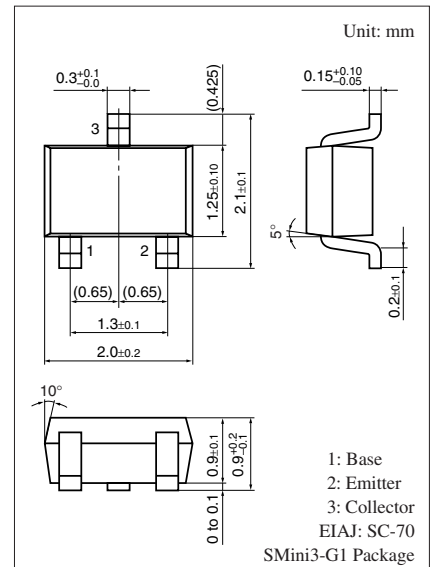
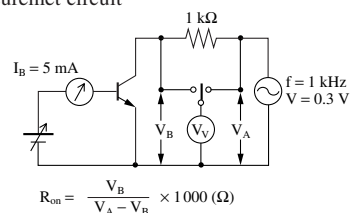
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 1\text{ mA}$, $I_B = 0$	20			V
Base-emitter voltage	V_{BE}	$V_{CE} = 2\text{ V}$, $I_C = 4\text{ mA}$		0.6		V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 50\text{ V}$, $I_E = 0$			1	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 25\text{ V}$, $I_C = 0$			1	μA
Forward current transfer ratio *1	h_{FE}	$V_{CE} = 2\text{ V}$, $I_C = 4\text{ mA}$	500		2 500	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 30\text{ mA}$, $I_B = 3\text{ mA}$			0.1	V
Transition frequency	f_T	$V_{CB} = 6\text{ V}$, $I_E = -4\text{ mA}$, $f = 200\text{ MHz}$		80		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$		4.5		pF
ON resistance *2	R_{on}			1		Ω

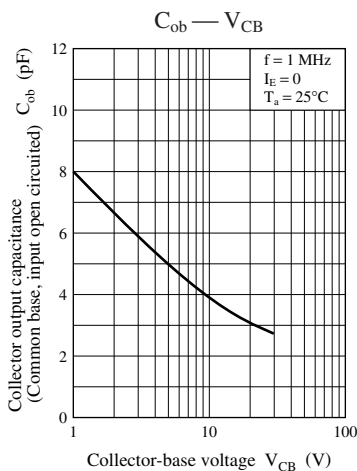
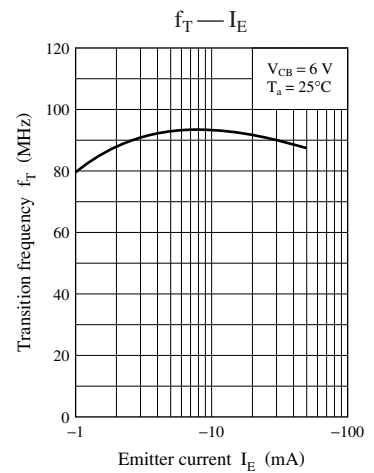
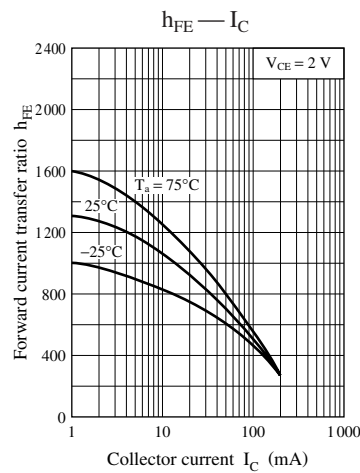
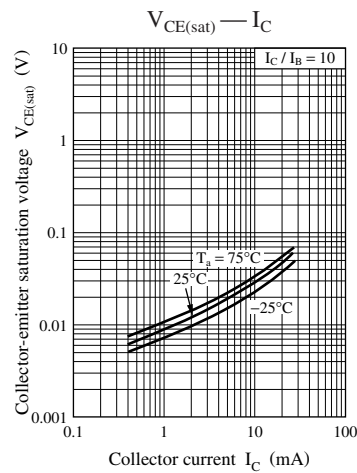
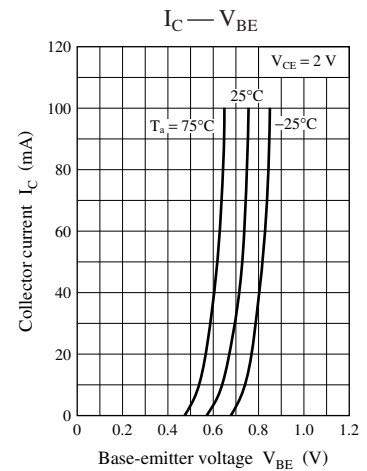
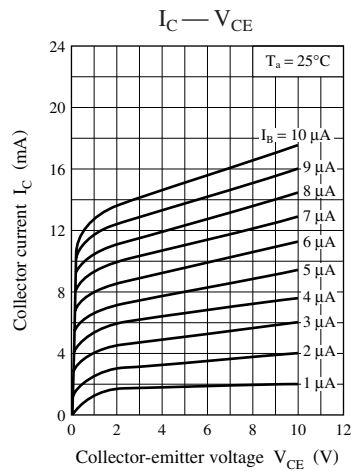
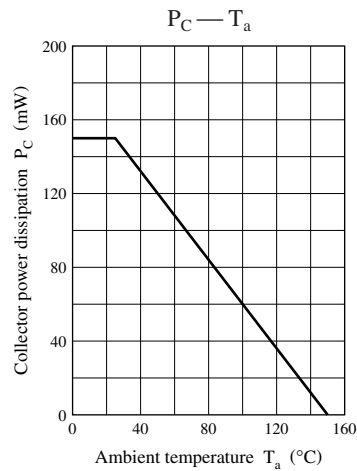
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Rank classification

Rank	S	T
h_{FE}	500 to 1 500	800 to 2 500

*2: R_{on} Measurement circuit

Marking symbol: 3W



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